											RE\	/ISIC	ONS													
LTR							D	ESC	RIPT	10N								C	ATE (M-RY)	IO-DA)	API	PROV	/ED	
Α	Table fMAX 10 an from numbe code	(Min d 11 15.5 er ir	n), I fr 5 ns	sub om to 4.	90 90 16 Ed	ip 9; MHz .5 ns itor	to	om 1 75 N Add	100 1Hz. "50	MHz t _r	to LH4	90 M , su the	Hz ā ıbgro mil:	nd oups itar	sub: 10 v d	grou and rawi	i 11 ing	1	1987 JULY 24			4	TRCod			
В	Techn Incre I. T throu chang 27014	ase able igh	d se e I t _{PHL}	f _M A	o an XX ^t incr	d ho est ease doc	ld t from max umen	ime 75 imu	, ι MHz n 1 ^c Cha	Dele z to imit ange	te t 60 s. in	ootr MHz . Made	ote Ta	able itor	·ial	t _{PHI}	_2	1	989	JAN	3		M i	MC	\delta	P
	IRRE	N7	r (A	GE	E C	OE	ÞΕ	67	726 T	68 T	Í														
CU REV		N7	r c	A	GE	E C	OE	ÞΕ	67	726	8															
REV		N T	г с	A	GE	C	OE	E	67	726	8															
REV	Г	N	Γ C	A	GE	C	OE	E	67	726	8															
REV SHEET REV SHEET	ī	EN7	Γ C		GE	C	OE B	E		726		В	В	В	В	В	В	В								
REV SHEET REV SHEET	TATUS	ENT			GE				В		В	B 7		B 9	B 10		B 12									
REV SHEET REV SHEET	TATUS HEETS	ENT	RE		GE	B 1	В	B 3	B 4	B 5	B 6	7	8		10	11	12	13 ELE (CTRO				CEN	ITER		
REV SHEET REV SHEET REV S OF SH	TATUS HEETS N/A ANDA MILI' DRA	ARD	RET	V EET		В 1 РВБ	B 2 PARE	B 3 BBy	B 4	B 5	B 6	7	8	9	10	DEFE	12 NSE RCUI NARY	ELEC DAY	IGIT	AL R, M	O 45 4 ADV	ANCE	D S0	НОТ	TKY	
REV SHEET REV SHEET OF SH	TATUS HEETS N/A ANDA	ARD TAF WIN G IS A	SHE SHE	ED ABL	E	B 1 PRE	B 2 PARE	B 3 BY BY G AP	B 4 4 ARY	B 5	B 6	7	8	9	10	DEFE	12 NSE RCUI NARY	DAY	TON,	AL R, M	ADVA	ANCE LITH	D S0	CHOT SILI	TKY	7:

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5962-E1130

DISTRIBUTION STATEMENT A. Approved for public release; distribution is unlimited.

ョ间 5902-80072012A 1共应向			
1. SCOPE			
1.1 <u>Scope</u> . This drawing descr with 1.2.1 of MIL-STD-883, "Provi non-JAN devices".			
1.2 Part number. The complete	part number shall	be as shown in the	e following example:
5962-86072	01	E	X
Drawing number	Device type (1.2.1)	Case outline (1.2.2)	Lead finish per MIL-M-38510
1.2.1 <u>Device type</u> . The device	type shall identi	fy the circuit fund	tion as follows:
<u>Device type</u> <u>Ge</u>	neric number	Circ	cuit function
01	54F169	Synchronous 4	-bit up/down binary counter
1.2.2 <u>Case outlines</u> . The case as follows:	outlines shall be	as designated in a	appendix C of MIL-M-38510, and
Outline letter	Cas	e outline	
E D F F 2 C	-2 (16-lead, .840" -5 (16-lead, .440" -2 (20 terminal, .	x 310" x .200"), c x .285" x .085"), 358" x .358" x .100	lual-in line package flat package "), square chip carrier package
1.3 Absolute maximum ratings.			
Supply voltage range Input voltage range Storage temperature Maximum power dissipation (Lead temperature (soldering Thermal resistance, junctio Junction temperature (T _J)-	P _D)	1.2 V do 65°C to 413 mW +300°C See MIL-W	minimum to +7.0 V dc maximum to +7.0 V dc +150°C C L-38510, appendix C
1.4 Recommended operating cond	itions.		
Supply voltage (Y _{CC}) Minimum high level input vo Maximum low level input vol Case operating temperature Minimum setup time, Dn to C	Itage (V_{IH}) tage (V_{IL})	2.0 V dc 0.8 V dc 55°C to	minimum to 5.5 V dc maximum
TC = $^{+}25^{\circ}\text{C}$ $^{-}7_{\text{C}}$ = $^{-}55^{\circ}\text{C}$, $^{+}125^{\circ}\text{C}$ Minimum hold time, Dn to CP		4.0 ns 4.5 ns	
T _C = +25°C		3.0 ns 3.5 ns	
1/ Maximum power dissipation is short circuit test; e.g., I ₀		CC, and must withst	and the added Pp due to
CTANDA DDIZED	SIZE		

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2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

- 2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.
 - 3. REQUIREMENTS
- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- $3.2\,$ Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Truth tables. The truth tables shall be as specified on figure 2.
 - 3.2.3 Logic diagram. The logic diagram shall be as specified on figure 3.
 - 3.2.4 Counting sequence. The counting sequence diagram shall be as specified on figure 4.
- 3.2.5 Test circuit and switching waveforms. The test circuit and switching waveforms shall be as specified on figure 5.

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Test	Symbol	Conditions -55°C < T _C < +125°C	Group A	Limi	Unit	
	<u> </u>	-55 C < T _C < +125 C unless otherwise specified	subgroups	Min	Max	
High level output voltage	V _{OH}	V _{CC} = 4.5 V; I _{OH} = -1.0 mA V _{IL} = 0.8 V; V _{IH} = 2.0 V	1, 2, 3	2.4		V
Low level output voltage	v _{oL}		1, 2, 3		0.5	٧
Input clamp voltage	V _{IC}	V _{CC} = 4.5 V I _{IN} = -18 mA	1, 2, 3		-1.2	V
High level input current	I I H1	V _{CC} = 5.5 V V _{IN} = 2.7 V	1, 2, 3		20	μА
J	I IH2	V _{CC} = 5.5 V V _{IN} = 7.0 V	1, 2, 3		100	μА
Low level input current	IIL	V _{CC} = 5.5 V CET input	1, 2, 3		-1.2	mA
		VIN = 0.5 V other inputs	1, 2, 3		-0.6	mA
Short circuit output current	108	V _{CC} = 5.5 V	 1, 2, 3 	-60	-150	mA
Supply current	ICC	 V _{CC} = 5.5 V	1, 2, 3		75	mA
Functional tests		 See 4.3.1c	7,8			
Maximum clock frequency	f _{MAX}] 9 	90		MHz
		C _L = 50 pF See figures 4 and 5	10, 11	60		MHz

See footnotes at end of table.

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5询"5962-86072012A"供应商 TABLE I. Electrical performance characteristics - Continued. Limits Conditions $-55^{\circ}\text{C} < T_{\text{C}} < +125^{\circ}\text{C}$ unless otherwise specified Group A Unit Symbol Test subgroups Min Max $V_{CC} = 5.0 \text{ V}$ $R_L = 500\Omega$ $C_L = 50 \text{ pF}$ 9 ns Propagation delay time, tpLH1 CP to Q_n (PE high or low) See figures 4 and 5 10, 11 12 ns 9 12 ns tPHL1 10, 11 16 ns 16 9 ns Propagation delay time, CP to TC tpLH2 21 10, 11 ns 9 12 ns tPHL2 10, 11 15 ns 9 6 Propagation delay time, CET to TC ns tpLH3 10, 11 ns ns tpHL3 10, 11 12 ns 15 Propagation delay time, U/D to TC t_{PLH4} 16.5 10, 11 ns 9 12 ns tPHL4 14 10, 11 ns Not more than one output should be shorted at a time, and the duration of the short circuit condition should not exceed 1 second. **STANDARDIZED** SIZE Α 5962-86072 **MILITARY DRAWING REVISION LEVEL** SHEET **DEFENSE ELECTRONICS SUPPLY CENTER** DAYTON, OHIO 45444

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	Case outlines	 E and F	2		
	Terminal number	 Terminal	symbol		
	1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20	U/D CP CP D0 D1 D2 D2 D3 CEP GND PE CET Q3 Q2 Q1 Q0 TC	NCD U/D CP DO DO DO DO DO DO DO DO DO DO DO DO DO		
	NC	= No conn	ection		
FIGUR	E l. <u>Term</u>	ninal conn	ections.		
STANDARDIZED	sız A			5	962-86072
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PE	CEP	CET	บ/ช	Action on rising clock edge
<u> </u> L	X	l X	l X	Load (D _n -Q _n)
 H	_	 L	 H	Count up (Increment)
ļ ļ н	ļ L	! L	 L	Count down (Decrement)
H	H	X H	X	No change (hold) No change (hold)

H = High voltage level

L = Low voltage level

X = Irrelevant

Operatiny		In	l Outputs 					
mode	СР	ี บ/ชั	CEP	CET	PE	o _n	Q _n	TC
Parallel load	† †	X	X X	X X	 1 1	1 h	 L H	See note See note
Count up	†	h	 	 1 	 h 	l X	Count up	 See note
Count down	†	1	1 1	1 1	l h	X	Count down	 See note
Hold (do nothing) l	† †	X X	i h	X h	l h l h	X X	q _n	 See note H

H = High voltage level steady state h = High voltage level one setup time prior to the Low-to-High clock transition

L = Low voltage level steady state

1 = Low voltage level one setup time prior the Low-to-High clock transition

X = Irrelevant

 \mathbf{q} = Lower case letters indicate the state of the referenced output prior to the

Low-to-high clock transition t = Low-to-high clock transition

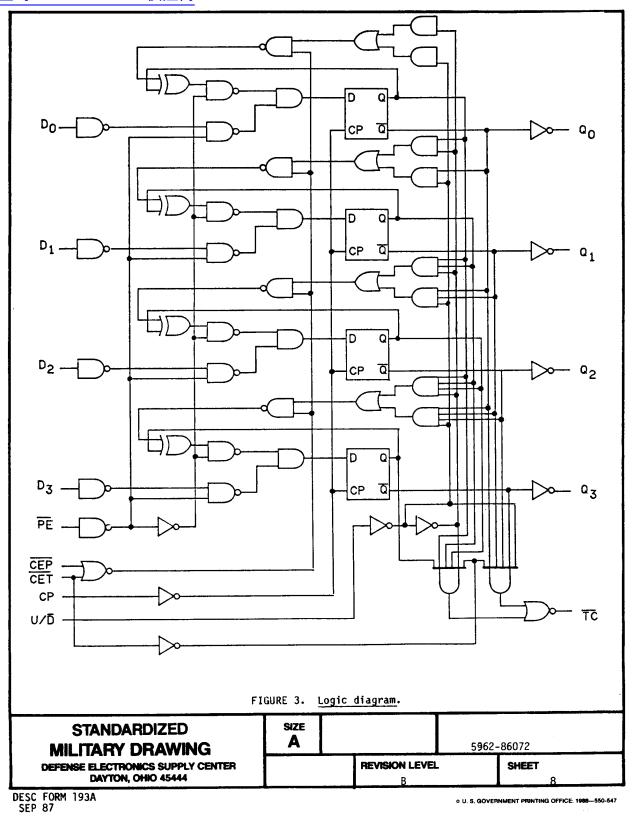
NOTE: TC is LOW when CET is LOW and the counter is at terminal count. Terminal count when counting up is HHHH, and terminal count when counting down is LLLL.

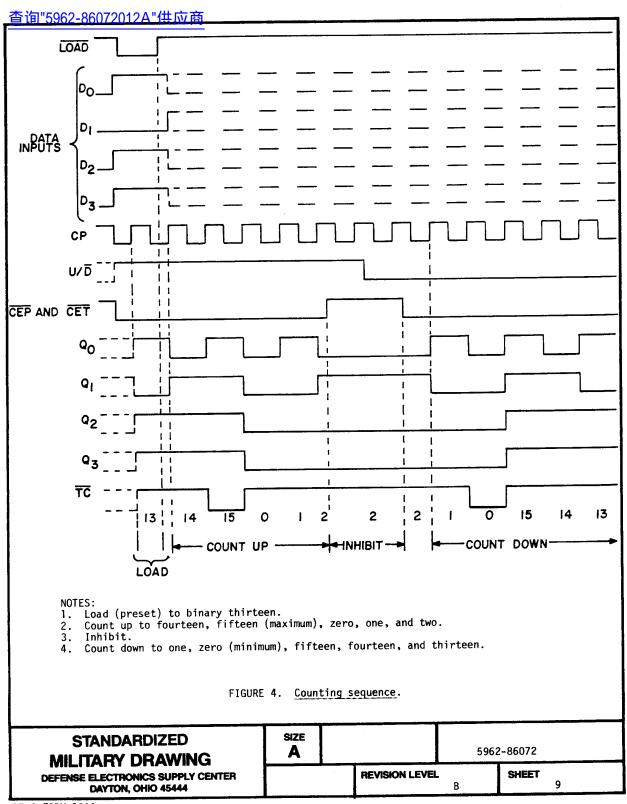
FIGURE 2. Truth tables.

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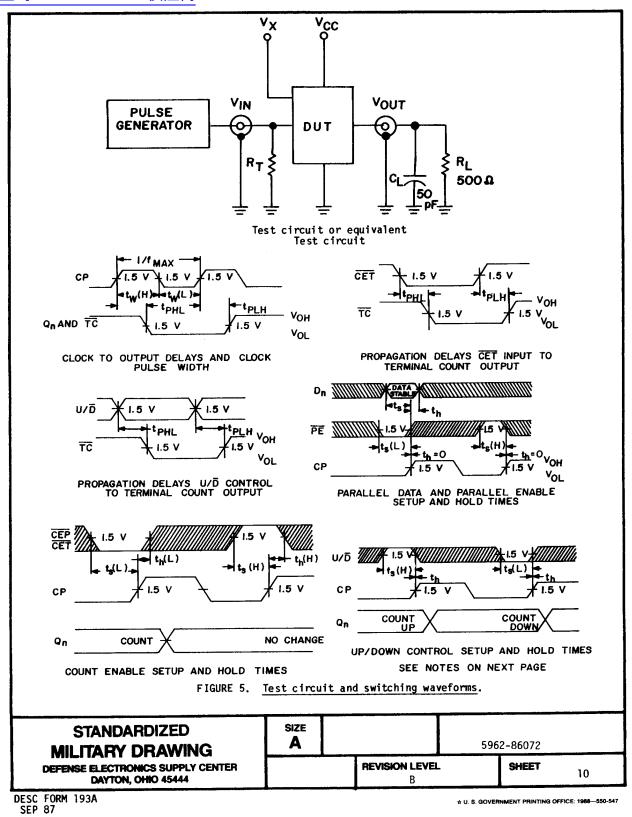
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Notes:

- 1. C_L = Load capacitance includes jig and probe capacitance.
- 2. R_T = Termination resistance should be equivalent to Z_{OUT} of pulse generators.
- 3. V_X = Unlocked pins must be held at ≤ 0.8 V_s , ≥ 2.7 V or open per function table.
- 4. All input pulses have the following characteristics: PRR \leq 1 MHz, duty cycle = 50%, tr = tf = 2.5 ns \pm 1 ns.
- 3.2.6 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 <u>Electrical performance characteristics</u>. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full case operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 <u>Certificate of conformance</u>. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).
- 3.8 <u>Verification and review.</u> DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. QUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 <u>Screening</u>. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.

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- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply:
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 4, 5, and 6 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - c. Subgroup 7 and 8 tests shall verify the truth table as specified on figure 2.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions method 1005 of MIL-STD-883:
 - Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
 Interim electrical parameters (method 5004)	
 Final electrical test parameters (method 5004)	1*,2,3,7,8,9
Group A test requirements (method 5005)	1,2,3,7,8,9, 10, 11
 Groups C and D end-point electrical parameters (method 5005)	1, 2, 3

^{*} PDA applies to subgroup 1.

- 5. PACKAGING
- 5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.
 - 6. NOTES
- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.

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- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.
- 6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

Military drawing part number	Vendor CAGE number	Vendor similar part number 1/
5962-8607201EX	18324 27014	54F169/BEA 54F169DMQB
5962-8607201FX	18324 27014	54F169/BFA 54F169FMQB
5962-86072012X	18324 27014	54F169/B2A 54F169LMQB

Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.

number	and address
18324	Signetics Corporation 4130 S. Market Court Sacramento, CA 95834
27014	National Semiconductor Corporation 333 Western Avenue South Portland, ME 04106

Vendor name

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DESC FORM 193A SEP 87 **Vendor CAGE**